

# GdSi<sub>2</sub> Structure:

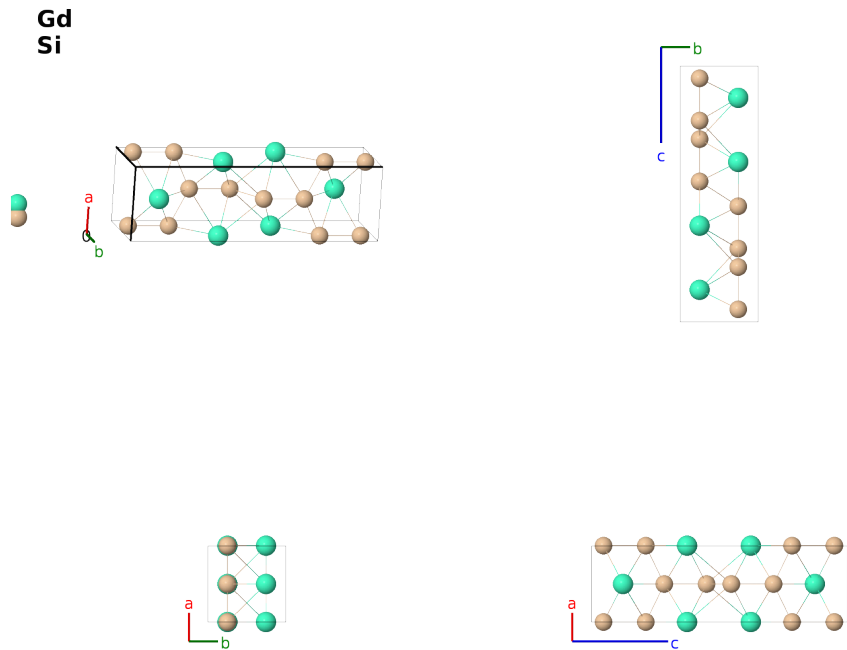
## AB2\_oI12\_74\_e\_2e-001

Cite this page as:

- H. Eckert, S. Divilov, M. J. Mehl, D. Hicks, A. C. Zettel, M. Esters, X. Campilongo, and S. Curtarolo, *The AFLOW Library of Crystallographic Prototypes: Part 4*, Comput. Mater. Sci. **240**, 112988 (2024), doi: 10.1016/j.commatsci.2024.112988.
- D. Hicks, M. J. Mehl, M. Esters, C. Osos, O. Levy, G. L. W. Hart, C. Toher, and S. Curtarolo, *The AFLOW Library of Crystallographic Prototypes: Part 3*, Comput. Mater. Sci. **199**, 110450 (2021), doi: 10.1016/j.commatsci.2021.110450.

<https://aflow.org/prototype-encyclopedia/EQ3C>

[https://aflow.org/prototype-encyclopedia/AB2\\_oI12\\_74\\_e\\_2e-001](https://aflow.org/prototype-encyclopedia/AB2_oI12_74_e_2e-001)



|                         |                                                                                                                              |
|-------------------------|------------------------------------------------------------------------------------------------------------------------------|
| Prototype               | GdSi <sub>2</sub>                                                                                                            |
| AFLOW prototype label   | AB2_oI12_74_e_2e-001                                                                                                         |
| ICSD                    | 291182                                                                                                                       |
| CCDC                    | 1723312                                                                                                                      |
| Pearson symbol          | oI12                                                                                                                         |
| Space group number      | 74                                                                                                                           |
| Space group symbol      | <i>Imma</i>                                                                                                                  |
| AFLOW prototype command | <code>aflow --proto=AB2_oI12_74_e_2e-001</code><br><code>--params=a,b/a,c/a,z<sub>1</sub>,z<sub>2</sub>,z<sub>3</sub></code> |

### Other compounds with this structure

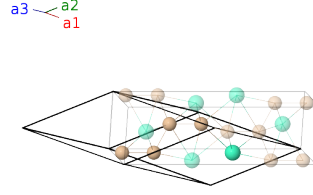
GeSi<sub>2</sub>, HoSi<sub>2</sub>, LaGe<sub>2</sub>, TbSi<sub>2</sub>, DySi<sub>1.4</sub>, GdSi<sub>1.4</sub>, NdSi<sub>1.4</sub>, PrSi<sub>1.4</sub>, SmSi<sub>1.4</sub>, YSi<sub>1.4</sub>

- (Zou, 2015) find that the Si-I site has 96.8% occupancy and the Si-II site has 81.2% occupancy, so the actual stoichiometry of their sample is  $\text{GdSi}_{1.78}$ .

---

### Body-centered Orthorhombic primitive vectors

$$\begin{aligned}\mathbf{a}_1 &= -\frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}b\hat{\mathbf{y}} + \frac{1}{2}c\hat{\mathbf{z}} \\ \mathbf{a}_2 &= \frac{1}{2}a\hat{\mathbf{x}} - \frac{1}{2}b\hat{\mathbf{y}} + \frac{1}{2}c\hat{\mathbf{z}} \\ \mathbf{a}_3 &= \frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}b\hat{\mathbf{y}} - \frac{1}{2}c\hat{\mathbf{z}}\end{aligned}$$




---

### Basis vectors

|                | Lattice<br>coordinates                                                                         |     | Cartesian<br>coordinates                              | Wyckoff<br>position | Atom<br>type |
|----------------|------------------------------------------------------------------------------------------------|-----|-------------------------------------------------------|---------------------|--------------|
| $\mathbf{B}_1$ | $= \left(z_1 + \frac{1}{4}\right) \mathbf{a}_1 + z_1 \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$  | $=$ | $\frac{1}{4}b\hat{\mathbf{y}} + cz_1\hat{\mathbf{z}}$ | (4e)                | Gd I         |
| $\mathbf{B}_2$ | $= -\left(z_1 - \frac{3}{4}\right) \mathbf{a}_1 - z_1 \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$ | $=$ | $\frac{3}{4}b\hat{\mathbf{y}} - cz_1\hat{\mathbf{z}}$ | (4e)                | Gd I         |
| $\mathbf{B}_3$ | $= \left(z_2 + \frac{1}{4}\right) \mathbf{a}_1 + z_2 \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$  | $=$ | $\frac{1}{4}b\hat{\mathbf{y}} + cz_2\hat{\mathbf{z}}$ | (4e)                | Si I         |
| $\mathbf{B}_4$ | $= -\left(z_2 - \frac{3}{4}\right) \mathbf{a}_1 - z_2 \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$ | $=$ | $\frac{3}{4}b\hat{\mathbf{y}} - cz_2\hat{\mathbf{z}}$ | (4e)                | Si I         |
| $\mathbf{B}_5$ | $= \left(z_3 + \frac{1}{4}\right) \mathbf{a}_1 + z_3 \mathbf{a}_2 + \frac{1}{4} \mathbf{a}_3$  | $=$ | $\frac{1}{4}b\hat{\mathbf{y}} + cz_3\hat{\mathbf{z}}$ | (4e)                | Si II        |
| $\mathbf{B}_6$ | $= -\left(z_3 - \frac{3}{4}\right) \mathbf{a}_1 - z_3 \mathbf{a}_2 + \frac{3}{4} \mathbf{a}_3$ | $=$ | $\frac{3}{4}b\hat{\mathbf{y}} - cz_3\hat{\mathbf{z}}$ | (4e)                | Si II        |

### References

- [1] J. D. Zou, J. Liu, and M. Yan, *Crystal structure and magnetic properties of  $\text{GdSi}_{1.78}$ ,  $\text{Gd}(\text{Si}_{0.684}\text{Ge}_{0.316})_{1.78}$ ,  $\text{GdGe}_{1.57}$ , and  $\text{GdSn}_2$  compounds*, J. Magn. Magn. Mater. **385**, 77–82 (2015), doi:10.1016/j.jmmm.2015.02.057.
- [2] W. B. Pearson, *A Handbook of Lattice Spacings and Structures of Metals and Alloys, Volume 2, International Series of Monographs on Metal Physics and Physical Metallurgy*, vol. 8 (Pergamon Press, Oxford, London, Edinburgh, New York, Toronto, Sydney, Paris, Braunschweig, 1967).

### First cited in

H. Eckert, S. Divilov, M. J. Mehl, D. Hicks, A. C. Zettel, M. Esters, X. Campilongo, and S. Curtarolo, *The AFLOW Library of Crystallographic Prototypes: Part 4*, Comput. Mater. Sci. **240**, 112988 (2024), doi: 10.1016/j.commatsci.2024.112988.